											RE	EVIS	ION	s												
LTR								DESC	RIP	<b>AOIT</b>	ı								DAT	Œ (YI	R-MO-	DA)	7	<b>NPPR</b>	OVE	·
																					1-100	DA)				
REV																										
SHEET	$\Box$		$oldsymbol{\mathbb{L}}$	$oxed{\int}$			$\prod$																			
REV		$oldsymbol{\mathbb{L}}$	$oldsymbol{\mathbb{I}}$	$oldsymbol{\mathbb{T}}$	$\perp$	I																				
SHEET	$\Box \Gamma$			$\prod$	$\int$		$\rfloor$																			
REV STA			REV		$oldsymbol{\mathbb{I}}$	$oldsymbol{\mathbb{L}}$	brack	$\Box$																		
OF SHEE	TS		SHEE	ET	1		2	3	4	5	6	7	8	9	10											
	DAR LITA AWI	RY NG S AVA	LABI	LE	) o () A	PPROPRAWI	E V	BY D BY	<u>ε</u>	. Q	es	01/	2	DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444  MICROCIRCUIT, LINEAR, LOW NOISE, HIGH SPEED, OPERATIONAL AMPLIFIER, MONOLITHI SILICON  SIZE CAGE CODE						;						
AND AND AND AND AMSC N	GENCIE MENT C	S OF	THE		R	]] EVISIO		AY 1		)					A	SHE			1			5962-90568				

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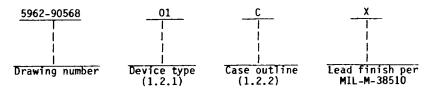
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DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

# SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device types. The device types shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01	0P-237A	Dual, low-offset, low noise, high speed operational amplifier
02	0P-237C	Dual, low-offset, low noise, high speed operational amplifier

1.2.2 <u>Case outline</u>. The case outline shall be as designated in appendix C of MIL-M-38510, and as follows:

Case outline Outline letter D-1 (14-lead, .785" x .310" x .200"), dual-in-

line package

1.3 Absolute maximum ratings. 1/

Output short circuit duration - - - - - - - Indefinite Differential input current 2/ - - - - - -  $\pm 25$  mA Differential input voltage range - - - - - - -  $\pm 0.7$  V dc Lead temperature (soldering, 60 seconds) - - - - -  $\pm 300$  °C Storage temperature range (T<sub>J</sub>) - - - - - - - - - -  $\pm 65$  °C to  $\pm 150$  °C Maximum power dissipation (P<sub>D</sub>) - - - - - - - 500 mW 3/ Thermal resistance, junction-to-case ( $\theta_{\rm JC}$ ) - - - - See MIL- $\overline{\rm M}$ -38510, appendix C

1.4 Recommended operating conditions.

Unless otherwise specified, all voltages are referenced to ground.

The inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds  $\pm 0.7$  V, the input current should be limited to 25 mA. 3/ For T<sub>A</sub> greater than 106°C, derate linearly at 11.3 mW/°C.

#### SIZE STANDARDIZED Α 5962-90568 **MILITARY DRAWING REVISION LEVEL DEFENSE ELECTRONICS SUPPLY CENTER**

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# 2. APPLICABLE DOCUMENTS

2.1 Government specification, standard, and bulletin. Unless otherwise specified, the following specification, standard, and bulletin of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

**SPECIFICATION** 

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

- Test Methods and Procedures for Microelectronics.

BULLETIN

**MILITARY** 

MIL-BUL-103

- List of Standardized Military Drawings (SMD's).

(Copies of the specification, standard, and bulletin required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

# 3. REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
- 3.2.1 Terminal connections and logic diagram. The terminal connections and logic diagram shall be as specified on figure 1.
  - 3.2.2 Case outline. The case outline shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.
- 3.5 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in MIL-BUL-103 (see 6.6 herein).

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	Symbol		Conditions 5°C < TA < +125° V <sub>S</sub> = ±15°V otherwise specif	1	Group A subgroups	Lir Min	nits       Max	Unit
Input offset voltage $1/$	۷10			01	1	 	80	μ۷
ļ				02			180	
 				01	2, 3		180	
		<del> </del>		02			350	
Average input offset	TC V <sub>IO</sub>			01	1, 2, 3		1.0	μ <b>۷</b> /
voltage drift <u>2</u> /				02			1.8	
Input offset current	110			01	1		35	nΑ
				02			75	
 				01	2, 3	ļ 	50	
		_		02		 	135	
Input bias current	IIB			01	1		±40	
 				02			±80	
 				01	2, 3		±60	
	., , .,			02			±150	
Power supply	PSRR	VS = ±4	V to ±18 V	01	1		10	μ <b>V</b> /
rejection ratio		R <sub>S</sub> = 50	75	02	ļ	<u> </u>	20	:
		V <sub>S</sub> = ±4	.5 V to ±18 V	01	2, 3		16	+
		R <sub>S</sub> = 50	Ω	02	<u> </u>		51	
	CMRR	VCM = ±	11 V	01	1	114		dB
ratio		RS = 50	Ω	02	1	100	 	
		VCM = ±	10 V	01	2, 3	108	 	
 		$R_S = 50$	Ω	02		94	 	

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Test	  Symbol 	   -55°C   V  (unless	Condition $ \begin{array}{ccc}  & & & & & & \\  & \leq & & & & & \\  & S & = & & & & & \\  & S & = & & & & & \\  & Otherwise \end{array} $	s 25°C specified)	   Device   types 	Group A  subgroups 		mits   Max	Unit
Input voltage range $3/$	I VR				   A11 	1	±11.0		   V 
	i   			•	All	2, 3	±10.0	   	 
Power consumption	PD	Each an	plifier, T	A = +25°C	01	1		140	mW
	! 				02			170	
Input offset voltage	ν <sub>0ς</sub>				01	1 1		80	   μV 
nia ce ii					02			300	İ
	! [	ļ			01	2, 3		180	
		<u> </u>			02			480	<u> </u>
Average noninverting bias current	I <sub>B</sub> +	I <sub>B</sub> + = I	B+A + IB+B		01	1		±40	nA
Dias current	!   	2		•	02			±90	! 
	   				01	2, 3		±60	   
					02			±170	į
Noninverting offset current	1 <sub>0S+</sub>	I <sub>0S+</sub> =	I <sub>B+A</sub> - I <sub>B+</sub>	В	01	1 1		±60	1   
Carrent		İ			02	<u> </u>		±130	į
					01	2, 3		±90	
	   			····	02			±250	
Inverting offset current	I <sub>0S-</sub>	I <sub>0S-</sub> =	I <sub>B-A</sub> - I <sub>B-</sub>	В	01	1 1		±60	   
current	   				02			±130	
	]   				01	2, 3		±90	! 
N= +	 				02			±250	
Gain-bandwith product $\frac{2}{}$	GBW	f = 10 A <sub>VCL</sub> >	kHz, TA = 5 <u>4</u> /	+25°C	   All 	   4   	35		MHz
ee footnotes at end of	table.								
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Test	Symbo1	Conditions	Device types	Group A		nits	!   Unit
		ol   Conditions   -55°C \le TA \le +125°C     VS = ±15 V    (unless otherwise specified)		subgroups   	   Min 	Max	   
Large signal voltage	AvoL	$ \begin{array}{l} 1 \\ 1 \\ 1 \end{array} V_0 = \pm 10 \ V, \ R_L \ge 2 \ k\Omega $	01	4	3000		   V/m\ 
			02		2000		ļ
			01	5, 6	1000		
			02		800		! !
		$V_0 = \pm 10 \text{ V}, R_{\text{L}} \ge 600\Omega$	01	4	1000		
			02	1	800		
Output voltage swing	V <sub>OP</sub>	   R <sub>L</sub> <u>&gt;</u> 2 kΩ	01	4	±12		i V
			02		±11.5		 
	į		01	5, 6	±11.5		 
	ļ		02	 	±10.5		
		R <sub>L</sub> ≥ 600Ω	   All		<b>±</b> 10		
Slew rate	SR	$R_L > 2 k \Omega$ , $A_{VCL} = 5$ , $T_A = +25 \degree C$	l All	† 7   7 	10	1	<b>V</b> /µ:
Input noise voltage	l E <sub>n</sub>	   f <sub>O</sub> = 10 Hz, T <sub>A</sub> = +25°C	01	7	ĺ	6.0	nV Hz
density	1 "	] - · · · · · · · · · · · · · · · · · ·	02	] 		9.0	Hz
		f <sub>o</sub> = 1,000 Hz, T <sub>A</sub> = +25°C	01			3,9	
			02	 		4.6	
Input noise current	In	f <sub>O</sub> = 10 Hz, T <sub>A</sub> = +25°C	01	7		4.5	pA, Hz
	ļ		02	! ! [		5.66	HZ
	-	f <sub>O</sub> = 1,000 Hz, T <sub>A</sub> = +25°C	01	! ! ! !	ļļ	0.7	
			02	! 		0.99	

I/ Input offset voltage measurements are performed by automated test equipment approximately 0.5 second after application of power.  $V_{10}$  is excluded from PDA.

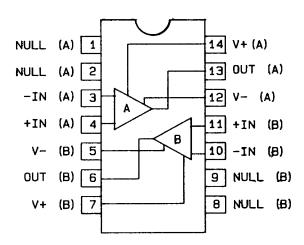
- $\underline{2}/$  If not tested, shall be guaranteed to the limits specified in table I herein.
- 3/ Guaranteed by CMRR test.
- $\underline{4}$ / The symbol A<sub>VCL</sub> stands for the closed-loop voltage gain.

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 $\frac{\text{Case C}}{\text{Device types 01 and 02}}$ 



NOTES: The V- supply terminals are both connected to the common substrate and must be tied to the same voltage. Both V- pins should be used.

FIGURE 1. Terminal connections and logic diagram (top view).

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- 3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.7 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.9 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
  - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening.</u> Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
  - a. Burn-in test, method 1015 of MIL-STD-883.
    - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.6 herein).
    - (2)  $T_A = +125$ °C, minimum.
  - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
  - 4.3.1 Group A inspection.
    - a. Tests shall be as specified in table II herein.
    - b. Subgroups 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
  - 4.3.2 Groups C and D inspections.
    - a. End-point electrical parameters shall be as specified in table II herein.
    - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
      - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.6 herein).
      - (2)  $T_A = +125^{\circ}C$ , minimum.
      - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups   (per method   5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*, 2, 3, 4
Group A test requirements (method 5005)	1, 2, 3, 4, 5, 6, 7
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

<sup>\*</sup>PDA applies to subgroup 1 (except  $V_{IO}$  is excluded from PDA).

# 5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

# 6. NOTES

- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).
- 6.4 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-ECS, telephone (513) 296-6022.
- 6.5 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone (513) 296-5375.

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6.6 Approved source of supply. An approved source of supply is listed in MIL-BUL-103.

Additional sources will be added to MIL-BUL-103 as they become available. The vendor listed in MIL-BUL-103 has agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-ECS. The approved source of supply listed below is for information purposes only and is current only to the date of the last action of this document.

Military drawing part number	Vendor   CAGE   number	Vendor   similar part   number <u>1</u> /
5962-9056801CX	64155	   OP-237AJ/883 
5962-9056802CX	64155	   OP-237CJ/883 

1/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

64155

Vendor name and address

Linear Technology, Inc. 1630 McCarthy Blvd. Milpitas, CA 95035-7487

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